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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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MJE15034 (NPN), MJE15035 (PNP)

Complementary Silicon Plastic Power Transistors

TO-220, NPN & PNP Devices

Complementary silicon plastic power transistors are designed for use as high-frequency drivers in audio amplifiers.

Features

- High Current Gain – Bandwidth Product
- TO-220 Compact Package
- Epoxy meets UL 94 V-0 @ 0.125 in
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	350	Vdc
Collector-Base Voltage	V_{CB}	350	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous	I_C	4.0	Adc
Collector Current – Peak	I_{CM}	8.0	Adc
Base Current	I_B	1.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	50 0.40	W W/ $^\circ\text{C}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	2.0 0.016	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	C	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.5	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

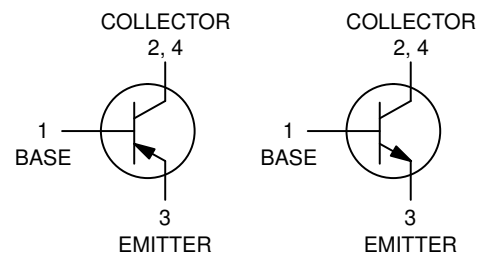


ON Semiconductor®

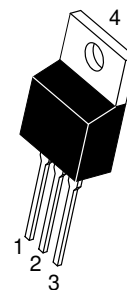
www.onsemi.com

4.0 AMPERES POWER TRANSISTORS COMPLEMENTARY SILICON 350 VOLTS, 50 WATTS

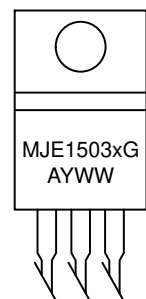
COMPLEMENTARY



MARKING DIAGRAM



TO-220
CASE 221A
STYLE 1



MJE1503x = Device Code
 x = 4 or 5
A = Location Code
Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MJE15034G	TO-220 (Pb-Free)	50 Units / Rail
MJE15035G	TO-220 (Pb-Free)	50 Units / Rail

MJE15034 (NPN), MJE15035 (PNP)

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage (Note 1)	($I_C = 10\text{ mAdc}, I_B = 0$)	$V_{CEO(sus)}$	350	-	Vdc
Collector Cutoff Current	($V_{CB} = 350\text{ Vdc}, I_E = 0$)	I_{CBO}	-	10	μAdc
Emitter Cutoff Current	($V_{BE} = 5.0\text{ Vdc}, I_C = 0$)	I_{EBO}	-	10	μAdc

ON CHARACTERISTICS (Note 1)

DC Current Gain	($I_C = 0.1\text{ Adc}, V_{CE} = 5.0\text{ Vdc}$) ($I_C = 0.5\text{ Adc}, V_{CE} = 5.0\text{ Vdc}$) ($I_C = 1.0\text{ Adc}, V_{CE} = 5.0\text{ Vdc}$) ($I_C = 2.0\text{ Adc}, V_{CE} = 5.0\text{ Vdc}$)	h_{FE}	100 100 50 10	- - - -	-
Collector-Emitter Saturation Voltage	($I_C = 1.0\text{ Adc}, I_B = 0.1\text{ Adc}$)	$V_{CE(sat)}$	-	0.5	Vdc
Base-Emitter On Voltage	($I_C = 1.0\text{ Adc}, V_{CE} = 5.0\text{ Vdc}$)	$V_{BE(on)}$	-	1.0	Vdc

DYNAMIC CHARACTERISTICS

Current Gain - Bandwidth Product (Note 2) ($I_C = 500\text{ mAdc}, V_{CE} = 10\text{ Vdc}, f_{test} = 1.0\text{ MHz}$)	f_T	30	-	MHz
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width $\leq 300\ \mu\text{s}$, Duty Cycle $\leq 2.0\%$.
2. $f_T = |h_{fe}| \cdot f_{test}$.

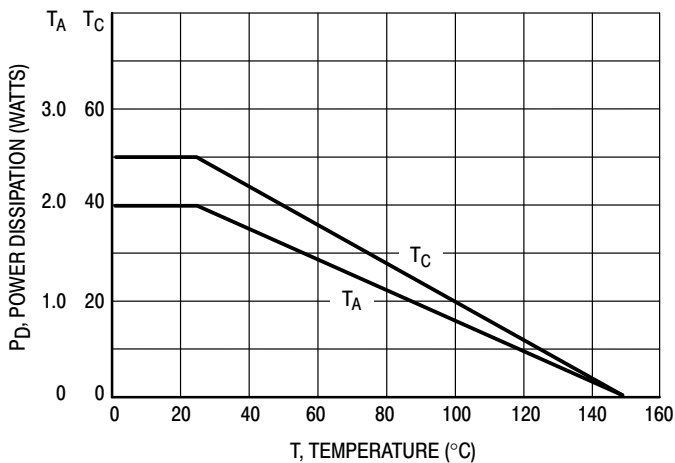


Figure 1. Power Derating

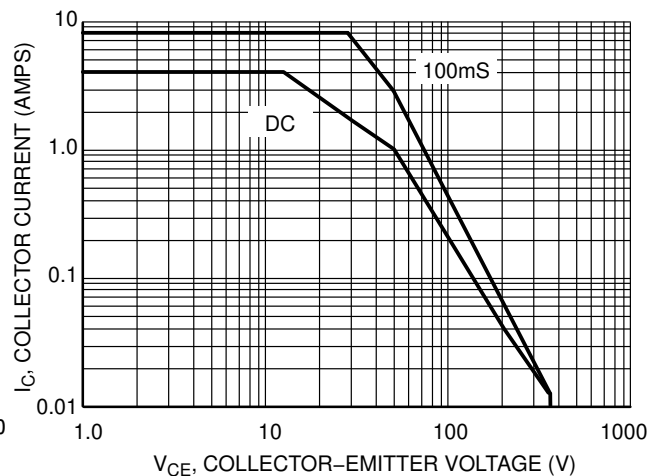


Figure 2. Active Region Safe Operating Area

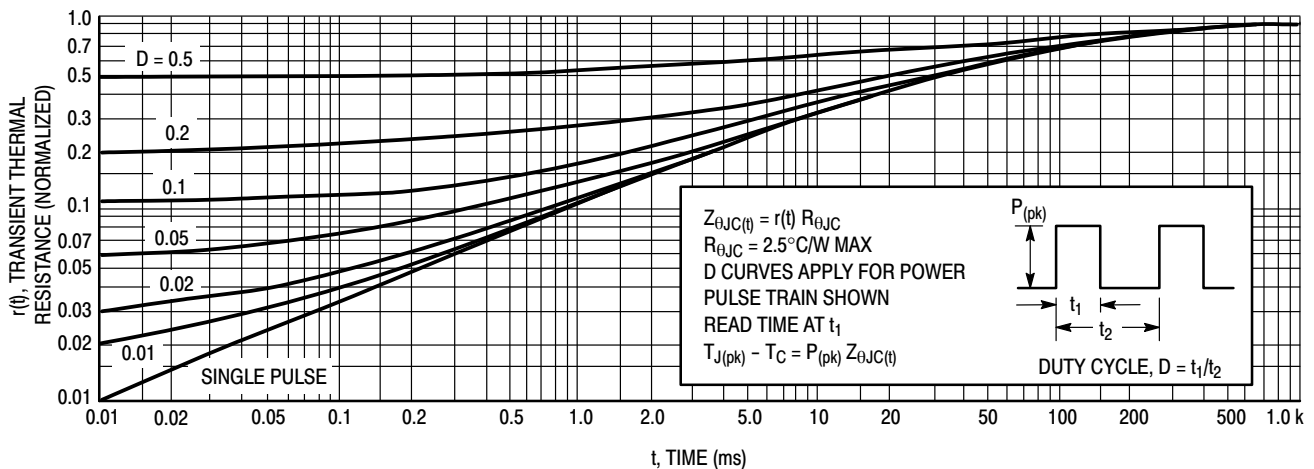
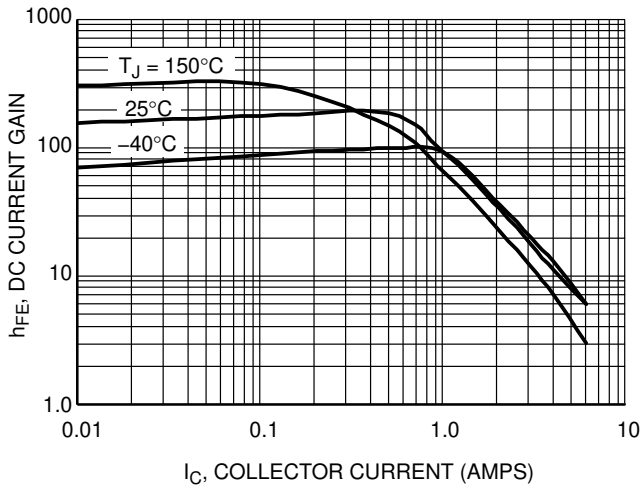
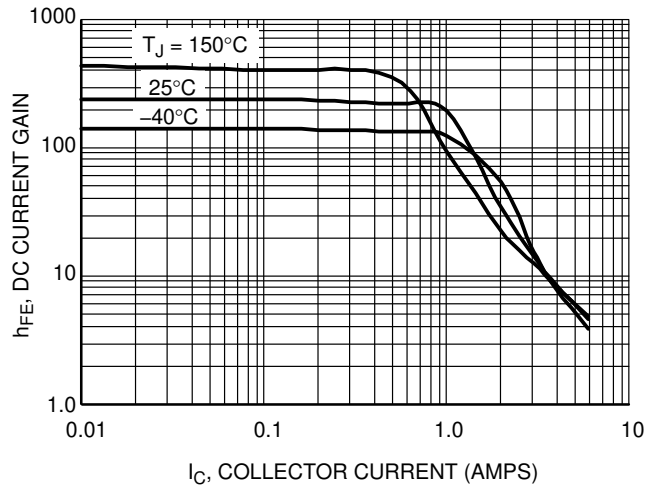


Figure 3. Thermal Response

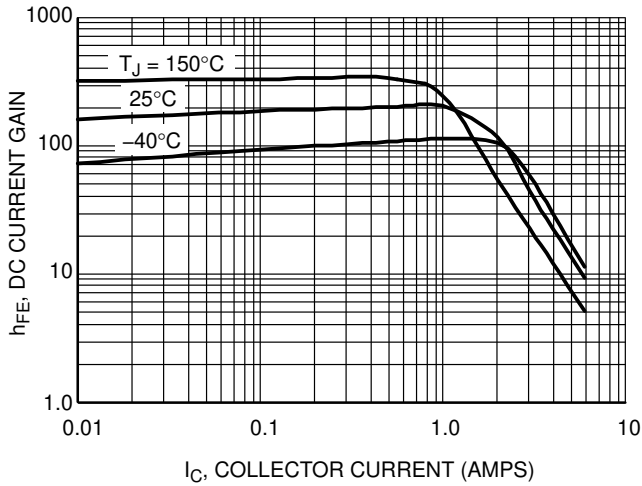
MJE15034 (NPN), MJE15035 (PNP)



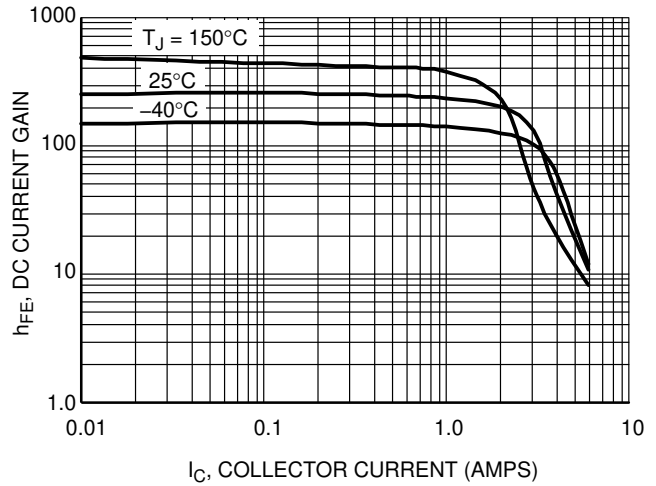
**Figure 4. DC Current Gain, $V_{CE} = 5.0$ V
NPN MJE15034**



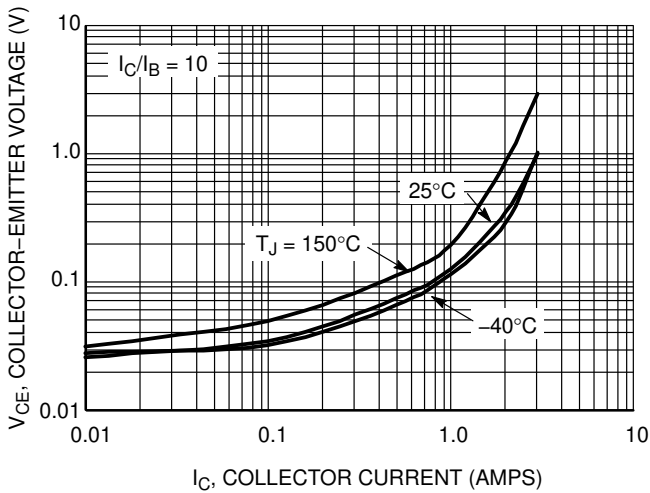
**Figure 5. DC Current Gain, $V_{CE} = 5.0$ V
PNP MJE15035**



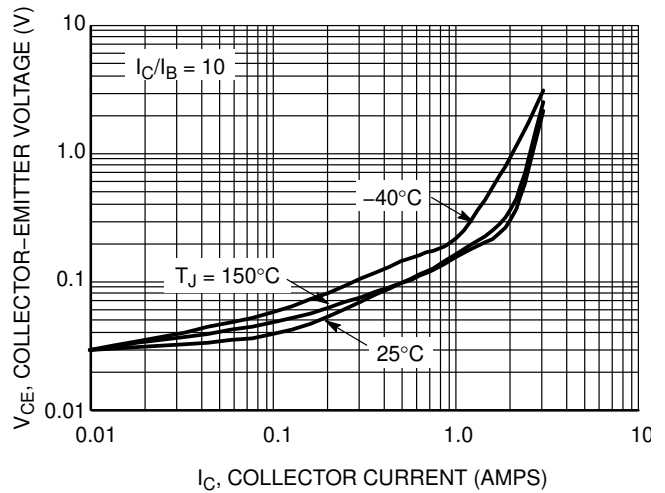
**Figure 6. DC Current Gain, $V_{CE} = 20$ V
NPN MJE15034**



**Figure 7. DC Current Gain, $V_{CE} = 20$ V
PNP MJE15035**

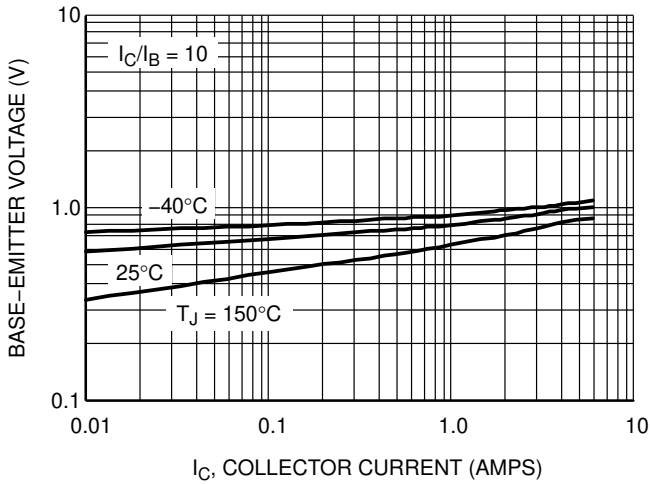


**Figure 8. $V_{CE(sat)}$
NPN MJE15034**

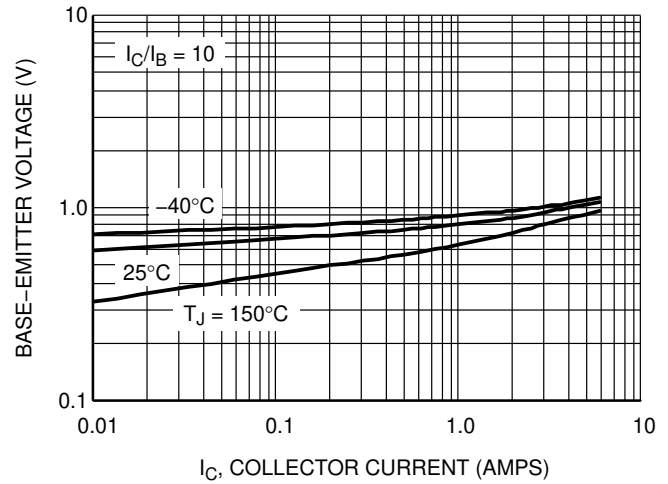


**Figure 9. $V_{CE(sat)}$
PNP MJE15035**

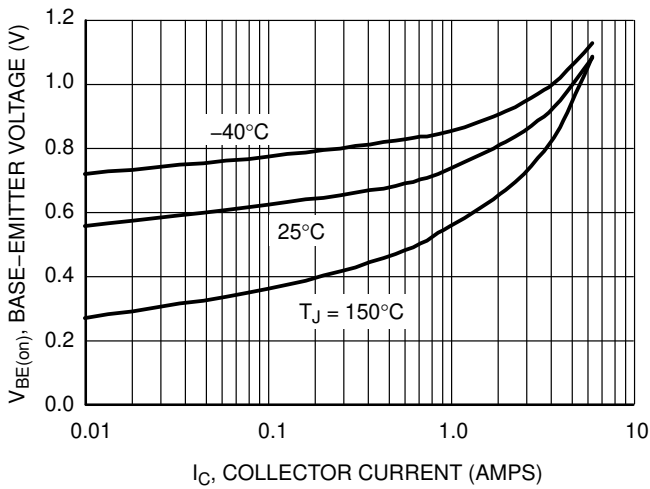
MJE15034 (NPN), MJE15035 (PNP)



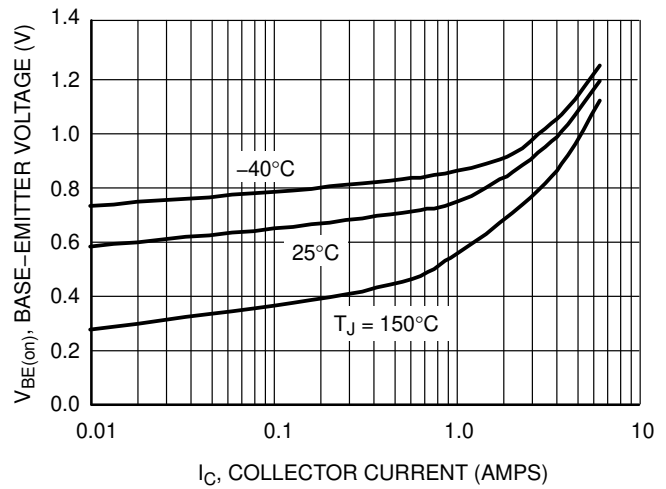
**Figure 10. $V_{BE(sat)}$
NPN MJE15034**



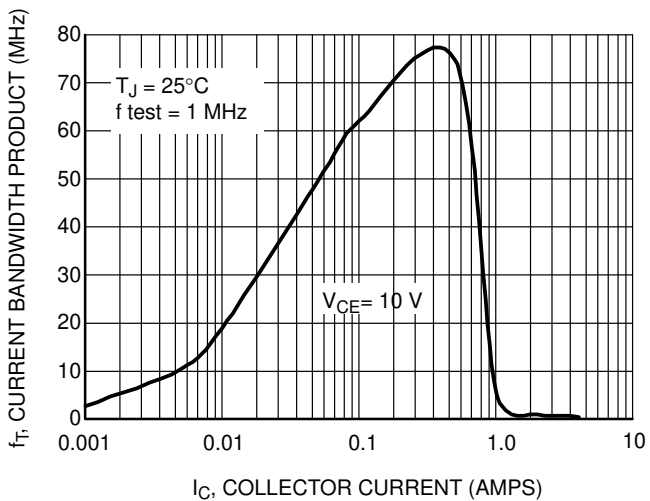
**Figure 11. $V_{BE(sat)}$
PNP MJE15035**



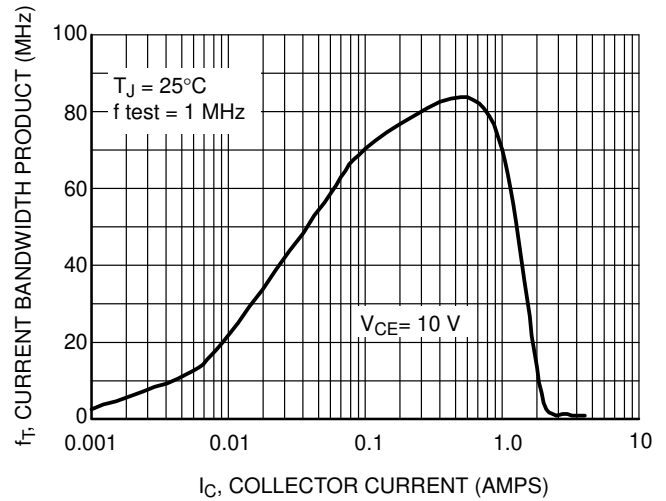
**Figure 12. $V_{BE(on)}$
NPN MJE15034**



**Figure 13. $V_{BE(on)}$
PNP MJE15035**



**Figure 14. Typical Current Gain Bandwidth Product
NPN MJE15034**

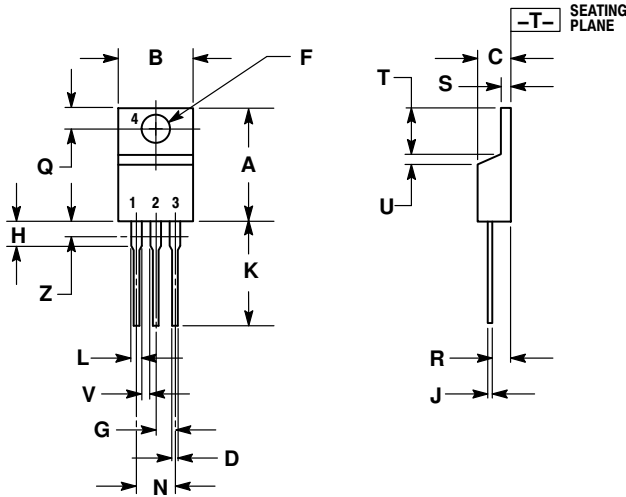


**Figure 15. Typical Current Gain Bandwidth Product
PNP MJE15035**

MJE15034 (NPN), MJE15035 (PNP)

PACKAGE DIMENSIONS

TO-220
CASE 221A-09
ISSUE AH



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.415	9.66	10.53
C	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 1:

- PIN 1. BASE
- COLLECTOR
- EMITTER
- COLLECTOR

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